

# Engineering Development Model

## RF Transformer

## JTX4-ED8055/1

Impedance Ratio : 4

### Important Note

This model has been designed, built and tested in our engineering department. Performance data represents model capability. At present it is a non-catalog model. On request, we can supply a final specification sheet, part number and price/delivery information.



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CASE STYLE : BH292

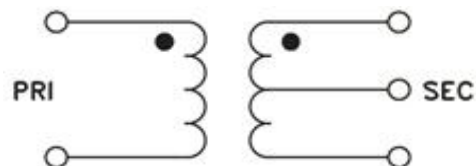
ELECTRICAL SPECIFICATIONS 50Ω @ +25°C					
Parameter		Min.	Typ.	Max.	Units
Frequency		1		400	MHz
Insertion Loss *	3 dB Bandwidth		1 - 400		MHz
	2 dB Bandwidth		1 - 400		MHz
	1 dB Bandwidth		1 - 300		MHz
Amplitude Unbalance	over 3dB Bandwidth		0.5		dB
	over 1dB Bandwidth		0.1		dB
Phase Unbalance	over 3dB Bandwidth		5.0		deg.
	over 1dB Bandwidth		1.00		deg.

### Note:

\* Insertion Loss is referenced to mid-band loss, 0.5dB typ.

MAXIMUM RATINGS	
Operating Temperature	-20°C to 85°C
Storage Temperature	-55°C to 100°C
RF Power	0.25 W
DC Current	30 mA

### Configuration : A



PIN CONNECTIONS	
PRIMARY DOT	4
PRIMARY	6
SECONDARY DOT	1
SECONDARY	3
SECONDARY CT	2
ISOLATE	5